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Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L5	2147	(retard\$5 stop\$4 prevent\$5 reduc\$5 eliminat\$5 block\$4) with diffus\$5 same ((carbon C) with (oxygen "O. sub.2"))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/07 15:41
L6	3	5 and ((iodine "I.sub.2") with alcohol\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/07 15:58
L7	64	5 and (ALD\$1 (atomic adj layer\$2 adj deposit\$5))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/07 15:08
L16	17714	(retard\$5 stop\$4 prevent\$5 reduc\$5 eliminat\$5 block\$4) with diffus\$5 with (dopant\$1 impurit\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/07 15:57
L17	177	16 same ((carbon C) with (oxygen "O. sub.2"))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/07 15:56
L19	94	17 same (heat\$3 anneal\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/07 15:57

Interference Search

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L10	2	(mono adj layer\$1) with (carbon C) with (oxygen "O.sub.2")	US-PGPUB	OR	OFF	2006/01/07 15:15



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## **Inventor Name Search Result**

Your Search was:

Last Name = CHAN

First Name = KEVIN K.

Application#	Patent#	Status	Date Filed	Title	Inventor Name
06923977	4689111	150	10/28/1986	PROCESS FOR PROMOTING THE INTERLAMINATE ADHESION OF POLYMERIC MATERIALS TO METAL SURFACES	CHAN, KEVIN K.
07049254	4797178	150	05/13/1987	PLASMA ETCH ENHANCEMENT WITH LARGE MASS INERT GAS	CHAN, KEVIN K.
07413357	5190792	150	09/27/1989	HIGH-THROUGHPUT, LOW- TEMPERATURE PROCESS FOR DEPOSITING OXIDES	CHAN, KEVIN K.
07435216	4978421	250		MONOLITHIC SILICON MEMBRANE DEVICE FABRICATION PROCESS	CHAN, KEVIN K.
07593141	5133986	150	10/05/1990	PLASMA ENHANCED CHEMICAL VAPOR PROCESSING SYSTEM USING HOLLOW CATHODE EFFECT	CHAN, KEVIN K.
07984816	Not Issued	161		HIGH-THROUGHPUT, LOW- TEMPERATURE PROCESS FOR DEPOSITING OXIDES	CHAN, KEVIN K.
08240060	5427630	150	05/09/1994	MASK MATERIAL FOR LOW TEMPERATURE SELECTIVE GROWTH OF SILICON OR SILICON ALLOYS	CHAN, KEVIN K.
08247170	5451535	250		METHOD FOR MANUFACTURING A MEMORY CELL	CHAN, KEVIN K.
08390132	5565031	150		METHOD FOR LOW TEMPERATURE SELECTIVE GROWTH OF SILICON OR SILICON ALLOYS	CHAN, KEVIN K.
08469650	5595600	150		LOW TEMPERATURE SELECTIVE GROWTH OF SILICON OR SILICON ALLOYS	CHAN, KEVIN K.
08587029	<u>5634973</u>	250	1	LOW TEMPERATURE SELECTIVE GROWTH OF SILICON OR SILICON ALLOYS	CHAN, KEVIN K.
08683329	Not	161	07/18/1996	SCALABLE MOS FIELD EFFECT	CHAN, KEVIN K.

	Issued			TRANSISTOR	
09207353	6350321	150	12/08/1998	UHV HORIZONTAL HOT WALL CLUSTER CVD/GROWTH DESIGN	CHAN, KEVIN K.
09272297	6365465	150		SELF-ALIGNED DOUBLE-GATE MOSFET BY SELECTIVE EPITAXY AND SILICON WAFER BONDING TECHNIQUES	CHAN, KEVIN K.
09312943	6255200	150	05/17/1999	POLYSILICON STRUCTURE AND PROCESS FOR IMPROVING CMOS DEVICE PERFORMANCE	CHAN, KEVIN K.
09337550	6238737	150		METHOD FOR PROTECTING REFRACTORY METAL THIN FILM REQUIRING HIGH TEMPERATURE PROCESSING IN AN OXIDIZING ATMOSPHERE AND STRUCTURE FORMED THEREBY	CHAN, KEVIN K.

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#### **Inventor Name Search Result**

Your Search was:

Last Name = CHEN First Name = HUAJIE

Application#					Inventor Name
10127196	6762469	150	04/19/2002	HIGH PERFORMANCE CMOS DEVICE STRUCTURE WITH MID-GAP METAL GATE	CHEN, HUAJIE
10249563	6780695	150	04/18/2003	BICMOS INTEGRATION SCHEME WITH RAISED EXTRINSIC BASE	CHEN, HUAJIE
10250100	6777302	150	06/04/2003	NITRIDE PEDESTAL FOR RAISED EXTRINSIC BASE HBT PROCESS	CHEN, HUAJIE
10250181	6749684	150	06/10/2003	METHOD FOR IMPROVING CVD FILM QUALITY UTILIZING POLYSILICON GETTERER	CHEN, HUAJIE
10345469	6844225	150	01/15/2003	SELF-ALIGNED MASK FORMED UTILIZING DIFFERENTIAL OXIDATION RATES OF MATERIALS	CHEN, HUAJIE
10448954	Not Issued	93	05/30/2003	SIGE LATTICE ENGINEERING USING A COMBINATION OF OXIDATION, THINNING AND EPITAXIAL REGROWTH	CHEN, HUAJIE
10604607	6891192	150	08/04/2003	STRUCTURE AND METHOD OF MAKING STRAINED SEMICONDUCTOR CMOS TRANSISTORS HAVING LATTICE- MISMATCHED SEMICONDUCTOR REGIONS UNDERLYING SOURCE AND DRAIN REGIONS	CHEN, HUAJIE
10604907	6924517	150	08/26/2003	THIN CHANNEL FET WITH RECESSED SOURCE/DRAINS AND EXTENSIONS	CHEN, HUAJIE
10605134	6906360	150		STRUCTURE AND METHOD OF MAKING STRAINED CHANNEL CMOS TRANSISTORS HAVING LATTICE- MISMATCHED EPITAXIAL EXTENSION AND SOURCE AND DRAIN REGIONS	CHEN, HUAJIE
10610612	Not	30	07/01/2003	Defect reduction by oxidation of silicon	СНЕМ, НИАЛЕ

	Issued				
10654232	6989058	150	09/03/2003	USE OF THIN SOI TO INHIBIT RELAXATION OF SIGE LAYERS	CHEN, HUAJIE
10689506	Not Issued	71	10/20/2003	High performance stress-enhanced MOSFETs using Si:C and SiGe epitaxial source/drain and method of manufacture	СНЕМ, НИАЛЕ
10708378	Not Issued	80	02/27/2004	HYBRID SOI/BULK SEMICONDUCTOR TRANSISTORS	CHEN, HUAJIE
10709239	Not Issued	71	04/23/2004	STRUCTURES AND METHODS FOR MANUFACTURING OF DISLOCATION FREE STRESSED CHANNELS IN BULK SILICON AND SOI CMOS DEVICES BY GATE STRESS ENGINEERING WITH SIGE AND/OR Si:C	CHEN, HUAJIE
10710255	6893936	150	06/29/2004	METHOD OF FORMING STRAINED SI/SIGE ON INSULATOR WITH SILICON GERMANIUM BUFFER	CHEN, HUAJIE
10710737	Not Issued	71	07/30/2004	CHEMICAL TREATMENT TO RETARD DIFFUSION IN A SEMICONDUCTOR OVERLAYER	CHEN, HUAJIE
10710826	Not Issued	41	08/05/2004	METHOD OF FORMING STRAINED SILICON MATERIALS WITH IMPROVED THERMAL CONDUCTIVITY	CHEN, HUAJIE
10711637	Not Issued	41	09/29/2004	STRUCTURE AND METHOD FOR MAKING STRAINED CHANNEL FIELD EFFECT TRANSISTOR USING SACRIFICIAL SPACER	CHEN, HUAJIE
10711899	Not Issued	80		ULTRA SHALLOW JUNCTION FORMATION BY EPITAXIAL INTERFACE LIMITED DIFFUSION	CHEN, HUAJIE
10728519	6972247	150	12/05/2003	METHOD OF FABRICATING STRAINED SI SOI WAFERS	CHEN, HUAJIE
10751207	Not Issued	61		Method of preventing surface roughening during hydrogen pre-bake of SiGe substrates using chlorine containing gases	CHEN, HUAJIE
10751208	6958286	150		METHOD OF PREVENTING SURFACE ROUGHENING DURING HYDROGEN PREBAKE OF SIGE SUBSTRATES	CHEN, HUAJIE
10795672	6916698	150		HIGH PERFORMANCE CMOS DEVICE STRUCTURE WITH MID-GAP METAL GATE	CHEN, HUAJIE
10818572	Not Issued	41		Method of forming high-quality relaxed SiGe alloy layers on bulk Si substrates	СНЕМ, НИАЛЕ
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10855915	Not Issued	61	05/27/2004	High-quality SGOI by annealing near the alloy melting point	CHEN, HUAJIE
10890765	Not Issued	41	07/14/2004	Ion implantation for suppression of defects in annealed SiGe layers	CHEN, HUAJIE
10905595	Not Issued	30	01/12/2005	LOW CONCENTRATION SIGE BUFFER DURING STRAINED SI GROWTH OF SSGOI MATERIAL FOR DOPANT DIFFUSION CONTROL AND DEFECT REDUCTION	СНЕМ, НИАЛЕ
10905598	Not Issued	30		IN SITU DOPED EMBEDDED SIGE EXTENSION AND SOURCE/DRAIN FOR ENHANCED PFET PERFORMANCE	CHEN, HUAJIE
10905978	Not Issued	30		STRUCTURE AND METHOD FOR MANUFACTURING PLANAR STRAINED Si/SiGe SUBSTRATE WITH MULTIPLE ORIENTATIONS AND DIFFERENT STRESS LEVELS	СНЕМ, НИАЛЕ
10908394	Not Issued	30	05/10/2005	EMBEDDED SILICON GERMANIUM USING A DOUBLE BURIED OXIDE SILICON-ON-INSULATOR WAFER	CHEN, HUAJIE
10943048	Not Issued	30	09/16/2004	Buffer layer for selective SiGe growth for uniform nucleation	CHEN, HUAJIE
10969718	Not Issued	30	10/20/2004	Self-aligned mask formed utilizing differential oxidation rates of materials	CHEN, HUAJIE
11037622	Not Issued	30		Structure and method for manufacturing strained silicon directly-on-insulator substrate with hybrid crystalline orientation and different stress levels	CHEN, HUAJIE
11081271	Not Issued			Method of making strained semiconductor transistors having lattice-mismatched semiconductor regions underlying source and drain regions	CHEN, HUAJIE
11268096	Not Issued	20		Use of thin SOI to inhibit relaxation of SiGe layers	CHEN, HUAJIE

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#### **Inventor Name Search Result**

Your Search was:

Last Name = HOLT First Name = JUDSON

Application#	Patent#	Status	Date Filed	Title	Inventor Name
10710245	Not Issued	30		DOPED NITRIDE FILM, DOPED OXIDE FILM AND OTHER DOPED FILMS	HOLT, JUDSON
10835949	Not Issued	94		MATERIAL FOR CONTACT ETCH LAYER TO ENHANCE DEVICE PERFORMANCE	HOLT, JUDSON
11253622	Not Issued	20		Material for contact etch layer to enhance device performance	HOLT, JUDSON
10710736	Not Issued	95	1	ULTRA-THIN BODY SUPER-STEEP RETROGRADE WELL (SSRW) FET DEVICES	HOLT, JUDSON R.
10710737	Not Issued	71	07/30/2004	CHEMICAL TREATMENT TO RETARD DIFFUSION IN A SEMICONDUCTOR OVERLAYER	HOLT, JUDSON R.
11029797	Not Issued	30	01/05/2005	Stressed field effect transistors on hybrid orientation substrate	HOLT, JUDSON R.
11088595	Not Issued	30		High performance field effect transistors on SOI substrate with stress-inducing material as buried insulator and methods	HOLT, JUDSON R.
11161964	Not Issued	30	08/24/2005	METHOD FOR POST-RIE PASSIVATION OF SEMICONDUCTOR SURFACES FOR EPITAXIAL GROWTH	HOLT, JUDSON R.
60732354	Not Issued	20		Implant damage control by in-situ C doping during SiGe epitaxy for device applications	HOLT, JUDSON ROBERT

Inventor Search Completed: No Records to Display.

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Scaren Another: Inventor	Holt	Judson	Search

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#### **Inventor Name Search Result**

Your Search was:

Last Name = LEE

First Name = WOO-HYEONG

		1			
Application#	Patent#	Status	Date Filed	Title	Inventor Name
08871024	Not Issued	161	1	FLOATING -GATE MEMORY DEVICE AND PROCESS FOR MAKING SAME	LEE, WOO-HYEONG
09041434	5923056	150	03/12/1998	ELECTRONIC COMONENTS WITH DOPED METAL OXIDE DIELECTRIC MATERIALS AND A PROCESS FOR MAKING ELECTRONIC COMPONENTS WITH DOPED METAL OXIDE DIELECTRIC MATERIALS	LEE, WOO-HYEONG
<u>10684596</u>	Not Issued	121	10/15/2003	Deposition of carbon and nitrogen doped poly silicon films, and retarded boron diffusion and improved poly depletion	LEE, WOO-HYEONG
10707878	Not Issued	41	01/20/2004	Polycrystalline Silicon Layer With Nano- grain Structure and Method of Manufacture	LEE, WOO-HYEONG
10710737	Not Issued	71	07/30/2004	CHEMICAL TREATMENT TO RETARD DIFFUSION IN A SEMICONDUCTOR OVERLAYER	LEE, WOO-HYEONG
10786901	Not Issued	41	02/25/2004	CMOS silicide metal gate integration	LEE, WOO-HYEONG
10905948	Not Issued	30	01/27/2005	TRANSISTOR HAVING HIGH MOBILITY CHANNEL AND METHODS	LEE, WOO-HYEONG
60027612	Not Issued	159	10/10/1996	FLOATING-GATE MEMORY DEVICE AND PROCESS FOR MAKING SAME	LEE, WOO-HYEONG

Inventor Search Completed: No Records to Display.

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	Lee	Woo-Hyeong	Search

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#### **Inventor Name Search Result**

Your Search was:

Last Name = MITCHELL

First Name = RYAN

Application#	Patent#	Status	Date Filed	Title	Inventor Name
09805380	Not Issued		03/13/2001		MITCHELL, RYAN J.
09805720	Not Issued	161		Method and system for analyzing and planning an inventory	MITCHELL, RYAN J.
11038975	Not Issued	30	01/19/2005	Voice-over-internet protocol gateway	MITCHELL, RYAN J.
60654328	Not Issued	20	02/17/2005	VOIP to wireless gateway	MITCHELL, RYAN J.
10674647	Not Issued	30		Thin buried oxides by low-dose oxygen implantation into modified silicon	MITCHELL, RYAN M.
10710737	Not Issued	71		CHEMICAL TREATMENT TO RETARD DIFFUSION IN A SEMICONDUCTOR OVERLAYER	MITCHELL, RYAN M.
10710826	Not Issued	41		METHOD OF FORMING STRAINED SILICON MATERIALS WITH IMPROVED THERMAL CONDUCTIVITY	MITCHELL, RYAN M.

Inventor Search Completed: No Records to Display.

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| Mitchell | Ryan M | Search |

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### **Inventor Name Search Result**

Your Search was:

Last Name = MO

First Name = RENEE

Application#	Patent#	Status	Date Filed	Title	Inventor Name
10249296	6790733	150	03/28/2003	PRESERVING TEOS HARD MASK USING COR FOR RAISED SOURCE- DRAIN INCLUDING REMOVABLE/DISPOSABLE SPACER	MO, RENEE T.
10605311	Not Issued	95	09/22/2003	METHOD FOR AVOIDING OXIDE UNDERCUT DURING PRE-SILICIDE CLEAN FOR THIN SPACER FETS	MO, RENEE T.
10710001	Not Issued	51	06/11/2004	Forming Shallow Trench Isolation Without the Use of CMP	MO, RENEE T.
<u>10710736</u>	Not Issued	95	07/30/2004	ULTRA-THIN BODY SUPER-STEEP RETROGRADE WELL (SSRW) FET DEVICES	MO, RENEE T.
10710737	Not Issued	71	07/30/2004	CHEMICAL TREATMENT TO RETARD DIFFUSION IN A SEMICONDUCTOR OVERLAYER	MO, RENEE T.
10710738	Not Issued	41		MANUFACTURABLE RECESSED STRAINED RSD STRUCTURE AND PROCESS FOR ADVANCED CMOS	MO, RENEE T.
10905683	Not Issued	30		NITRIDATION OF STI FILL OXIDE TO PREVENT THE LOSS OF STI FILL OXIDE DURING MANUFACTURING PROCESS	MO, RENEE T.
10907061	Not Issued	30		CLUSTERED SURFACE PREPARATION FOR SILICIDE AND METAL CONTACTS	MO, RENEE T.
10942303	Not Issued	71	09/16/2004	Method for monitoring lateral encroachment of spacer process on a CD SEM	MO, RENEE T.
11266855	Not Issued	41		Method for avoiding oxide undercut during pre-silicide clean for thin spacer FETs	MO, RENEE T.
11177246	Not Issued	20	07/07/2005	Positron therapy of inflammation, infection and disease	MOADEL, RENEE M.
60586366	Not	159	07/08/2004	Positron therapy of inflammation, infection	MOADEL, RENEE M.

	Issued			an disease	
10097461	<u>6681508</u>	150	03/14/2002	VISUAL DISPLAY DEVICE	MONTEIRO, RENEE A.
60275738	Not Issued	159	03/14/2001	Color geyser lamp	MONTEIRO, RENEE A.
06841146	Not Issued	161	1	BONDING OF ARTICLES TO METALLIZED SUBSTRATES	MOORE, RENEE D.
09204449	6132051	250	12/03/1998	MIRROR ATTACHMENT	MORELL, RENEE
60334324	Not Issued	159		Methods to inhibit thiol-mediated biocatalysis	MOSI, RENEE
60120618	Not Issued	159	1	METALLO-BETA-LACTAMASE INHIBITORS	MOSI, RENEE MARIE

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#### **Inventor Name Search Result**

Your Search was:

Last Name = MOCUTA

First Name = DAN

	D 4 4/1	C	D . E:	m: a	
Application#	Patent#	Status	Date Filed	Title	Inventor Name
10250181	6749684	150	06/10/2003	METHOD FOR IMPROVING CVD FILM QUALITY UTILIZING POLYSILICON GETTERER	MOCUTA, DAN
10127196	<u>6762469</u>	150	04/19/2002	HIGH PERFORMANCE CMOS DEVICE STRUCTURE WITH MID-GAP METAL GATE	MOCUTA, DAN M.
10707840	Not Issued	41	01/16/2004	Protecting Silicon Germanium Sidewall with Silicon for Strained Silicon/Silicon Germanium MOSFETs	MOCUTA, DAN M.
10710737	Not Issued	71	07/30/2004	CHEMICAL TREATMENT TO RETARD DIFFUSION IN A SEMICONDUCTOR OVERLAYER	MOCUTA, DAN M.
10751207	Not Issued	61	01/02/2004	Method of preventing surface roughening during hydrogen pre-bake of SiGe substrates using chlorine containing gases	MOCUTA, DAN M.
10751208	6958286	150	01/02/2004	METHOD OF PREVENTING SURFACE ROUGHENING DURING HYDROGEN PREBAKE OF SIGE SUBSTRATES	MOCUTA, DAN M.
10795672	6916698	150		HIGH PERFORMANCE CMOS DEVICE STRUCTURE WITH MID-GAP METAL GATE	MOCUTA, DAN M.
10954838	Not Issued	30		Structure and method for manufacturing MOSFET with super-steep retrograded island	MOCUTA, DAN M.

Inventor Search Completed: No Records to Display.

	Last Name	First Name	
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### **Inventor Name Search Result**

Your Search was:

Last Name = RAUSCH First Name = WERNER

Application#	Patent#				Inventor Name
<u>06124504</u>	4265677	150	02/25/1980	PHOSPHATIZING PRIOR TO CATHODIC ELECTROPAINTING	RAUSCḤ, WERNER
06258171	Not Issued	161	04/27/1981	PHOSPHATIZING	RAUSCH, WERNER
06337916	4389260	150	01/08/1982	COMPOSITION AND PROCESS FOR THE PHOSPHATISING OF METALS	RAUSCH, WERNER
06373475	4419199	150	04/30/1982	PROCESS FOR PHOSPHATIZING METALS	RAUSCH, WERNER
06593985	Not Issued	161	1	PROCESS AND COMPOSITION FOR PHOSPHATING METAL SURFACES	RAUSCH, WERNER
06600587	4559087	250	i I	PROCESS FOR PHOSPHATING METALS	RAUSCH, WERNER
06601184	Not Issued	161	04/17/1984	PROTECTING METALS FROM CORROSION	RAUSCH, WERNER
06653504	4547269	150	09/21/1984	METHOD OF ELECTRODEPOSITING ZINC ON STEEL PRIOR TO PHOSPHATING	RAUSCH, WERNER
06708463	4637838	250	! I	PROCESS FOR PHOSPHATING METALS	RAUSCH, WERNER
07092951	4849031	150		PROCESS OF PRODUCING PHOSPHATE COATINGS ON METAL SURFACES	RAUSCH, WERNER
<u>07106165</u>	4867853	150	1	PROCESS OF PRODUCING PHOSPHATE COATINGS	RAUSCH, WERNER
07156777	Not Issued	166		PROCESS OF PREPARING WORKPIECES OF ALUMINUM OR ALLOYS THEREOF FOR BEING PAINTED	RAUSCH, WERNER
07178124	Not Issued	166	04/06/1988	PROCESS OF PROSPHATING BEFORE ELECTROIMMERSION PAINTING	RAUSCH, WERNER
07230767	Not Issued	161	08/10/1988	PROCESS FOR PHOSPHATING METAL	RAUSCH, WERNER

07259158	Not Issued	161	10/18/1988	PROCESS OF FORMING PHOSPHATE COATINGS	RAUSCH, WERNER
07305214	4950339	250	02/01/1989	PROCESS OF FORMING PHOSPHATE COATINGS ON METALS	RAUSCH, WERNER
07369743	5024707	150	06/22/1989	PROCESS OF DECREASING THE INCRUSTATION IN PHOSPHATING PLANTS	RAUSCH, WERNER
07395478	Not Issued	166	08/18/1989	PHOSPHATING PROCESS	RAUSCH, WERNER
<u>07398185</u>	Not Issued	166	08/24/1989	METHOD OF APPLYING PHOSPHATE COATINGS	RAUSCH, WERNER
07428013	Not Issued	166	III I	PROCESS OF PHOSPHATING BEFORE ELECTROIMMERSION PAINTING	RAUSCH, WERNER
07456191	Not Issued	161	12/15/1989	PROCESS OF PREPARING WORKPIECES OF ALUMINUM OR ALLOYS THEREOF FOR BEING PAINTED	RAUSCH, WERNER
07484730	Not Issued	164		PROCESS FOR A PASSIVATING POSTRINSING OF PHOSPHATE LAYERS	RAUSCH, WERNER
07570350	5203930	150	11	PROCESS OF FORMING PHOSPHATE COATINGS ON METAL SURFACES	RAUSCH, WERNER
07570421	Not Issued	166	08/21/1990	PROCESS OF PRODUCING PHOSPHATE COATINGS ON METALS	RAUSCH, WERNER
07629076	5236565	250		PROCESS OF PHOSPHATING BEFORE ELECTROIMMERSION PAINTING	RAUSCH, WERNER
07645159	Not Issued	166	01/24/1991	COMPOSITION AND PROCESS FOR A PASSIVATING POSTRINSING OF CONVERSION LAYERS	RAUSCH, WERNER
<u>07683106</u>	5152849	150	04/10/1991	PHOSPHATING PROCESS	RAUSCH, WERNER
07691129	Not Issued	166	I	PROCESS FOR PHOSPHATING METAL SURFACES	RAUSCH, WERNER
07759840	Not Issued	161		METHOD OF APPLYING PHOSPHATE COATINGS	RAUSCH, WERNER
07793220	Not Issued	163		PROCESS FOR PRODUCING PHOSPHATE COATINGS ON METALS	RAUSCH, WERNER
07977668	Not Issued	161	II I	METHOD OF APPLYING PHOSPHATE COATINGS	RAUSCH, WERNER
07978193	5294266	150	II I	PROCESS FOR A PASSIVATING POSTRINSING OF CONVERSION LAYERS	RAUSCH, WERNER

08797904	6022766	150	02/10/1997	SEMICONDUCTOR STRUCTURE INCORPORATING THIN FILM TRANSISTORS, AND METHODS FOR ITS MANUFACTURE	RAUSCH, WERNER
<u>09231615</u>	6188122	150	01/14/1999	BURIED CAPACITOR FOR SILICON- ON-INSULATOR STRUCTURE	RAUSCH, WERNER
09239327	6521947	150	01/28/1999	METHOD OF INTEGRATING SUBSTRATE CONTACT ON SOI WAFERS WITH STI PROCESS	RAUSCH, WERNER
09377331	6686629	150	08/18/1999	SOI MOSFETS EXHIBITING REDUCED FLOATING-BODY EFFECTS	RAUSCH, WERNER
09707305	6337253	150	11/07/2000	Process of making buried capacitor for silicon-on-insulator structure	RAUSCH, WERNER
09717971	6303450	150	11/21/2000	Novel CMOS device structures and method of making same	RAUSCH, WERNER
09770788	6713791	150	01/26/2001	T-RAM ARRAY HAVING A PLANAR CELL STRUCTURE AND METHOD FOR FABRICATING THE SAME	RAUSCH, WERNER
09875842	6432777	150	06/06/2001	METHOD FOR INCREASING THE EFFECTIVE WELL DOPING IN A MOSFET AS THE GATE LENGTH DECREASES	RAUSCH, WERNER
10713447	Not Issued	71	11	CMOS well structure and method of forming the same	RAUSCH, WERNER
10732277	Not Issued	41		SOI MOSFETS exhibiting reduced floating-body effects	RAUSCH, WERNER
11164515	Not Issued	19		CMOS CIRCUITS INCORPORATING PASSIVE ELEMENTS OF LOW CONTACT RESISTANCE, AND METHODS OF FORMING SAME	RAUSCH, WERNER
09547893	6624459	150		SILICON ON INSULATOR FIELD EFFECT TRANSISTOR HAVING SHARED BODY CONTACT	RAUSCH, WERNER A.
09589719	6429482	150	06/08/2000	HALO-FREE NON-RECTIFYING CONTACT ON CHIP WITH HALO SOURCE/DRAIN DIFFUSION	RAUSCH, WERNER A.
10064305	6750109	150		HALO-FREE NON-RECTIFYING CONTACT ON CHIP WITH HALO SOURCE/DRAIN DIFFUSION	RAUSCH, WERNER A.
10250047	6887798		05/30/2003	STI STRESS MODIFICATION BY NITROGEN PLASMA TREATMENT FOR IMPROVING PERFORMANCE IN SMALL WIDTH DEVICES	RAUSCH, WERNER A.
10453080	6930030	150	11	METHOD OF FORMING AN ELECTRONIC DEVICE ON A RECESS	RAUSCH, WERNER A.

				 IN THE SURFACE OF A THIN FILM OF SILICON ETCHED TO A PRECISE THICKNESS	
104607	717	6815282	150	SILICON ON INSULATOR FIELD EFFECT TRANSISTOR HAVING SHARED BODY CONTACT	RAUSCH, WERNER A.
106051	00	Not Issued	71	A RAISED SOURFCE DRAIN MOSFET WITH NOTCH FORMED ON TOP OF GATE STRUCTURE FILLED WITH A DIELECTRIC PLUG	RAUSCH, WERNER A.

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### **Inventor Name Search Result**

Your Search was:

Last Name = RONSHEIM

First Name = PAUL

Application#	Patent#	Status	Date Filed	Title	Inventor Name	
07912945	Not Issued	161	07/13/1992	HETEROJUNCTION BIPOLAR TRANSISTOR WITH SELF-ALIGNED RETROGRADE EMITTER PROFILE	RONSHEIM, PAUL	
08346209	5656514	150	11/22/1994	METHOD OF MAKING HETEROJUNCTION BIPOLAR TRANSISTOR WITH SELF-ALIGNED RETROGRADE EMITTER PROFILE	RONSHEIM, PAUL	
10250181	6749684	150	06/10/2003	METHOD FOR IMPROVING CVD FILM QUALITY UTILIZING POLYSILICON GETTERER	RONSHEIM, PAUL	
09559880	6399434	150	1	DOPED STRUCTURES CONTAINING DIFFUSION BARRIERS	RONSHEIM, PAUL A.	
09734754	6509241	150	12/12/2000	PROCESS FOR FABRICATING AN MOS DEVICE HAVING HIGHLY- LOCALIZED HALO REGIONS	RONSHEIM, PAUL A.	
09866397	Not Issued	161		Reducing threshold voltage roll-up/roll-off effect for MOSFETS	RONSHEIM, PAUL A.	
09875072	6387782	150		PROCESS OF FORMING AN ULTRA- SHALLOW JUNCTION DOPANT LAYER HAVING A PEAK CONCENTRATION WITHIN A DIELECTRIC LAYER	RONSHEIM, PAUL A.	
09924014	6635517	150		USE OF DISPOSABLE SPACER TO INTRODUCE GETTERING IN SOI LAYER	RONSHEIM, PAUL A.	
10710737	Not Issued	71	07/30/2004	CHEMICAL TREATMENT TO RETARD DIFFUSION IN A SEMICONDUCTOR OVERLAYER	RONSHEIM, PAUL A.	
10762279	Not Issued	160		Method for manufacturing a MOSFET device	RONSHEIM, PAUL A.	
07652339	<u>5385850</u>	150		METHOD OF FORMING A DOPED REGION IN A SEMICONDUCTOR SUBSTRATE UTILIZING A SACRIFICIAL EPITAXIAL SILICON	RONSHEIM, PAUL A.	

				LAYER	
07710498	5194397	150	06/05/1991	METHOD FOR CONTROLLING INTERFACIAL OXIDE AT A POLYCRYSTALLINE/ MONOCRYSTALLINE SILICON INTERFACE	RONSHEIM, PAUL A.
<u>08457084</u>	5616513	250	15	SHALLOW TRENCH ISOLATION WITH SELF ALIGNED PSG LAYER	RONSHEIM, PAUL A.
09153986	6114257	150		PROCESS FOR MODIFIED OXIDATION OF A SEMICONDUCTOR SUBSTRATE USING CHLORINE PLASMA	RONSHEIM, PAUL A.
09213674	6194736	150	12/17/1998	QUANTUM CONDUCTIVE RECRYSTALLIZATION BARRIER LAYERS	RONSHEIM, PAUL A.
09458530	6329704	150	12/09/1999	ULTRA-SHALLOW JUNCTION DOPANT LAYER HAVING A PEAK CONCENTRATION WITHIN A DIELECTRIC LAYER	RONSHEIM, PAUL A.
09968793	Not Issued	161		Method for fabricating different gate oxide thickness within the same chip	RONSHEIM, PAUL ANDREW
09090735	Not Issued	161	06/04/1998	METHOD FOR FABRICATING DIFFERENT GATE OXIDE THINKNESSES WITHIN THE SAME CHIP	RONSHEIM, PAUL ANDREW
09231617	6335262	150	01/14/1999	METHOD FOR FABRICATING DIFFERENT GATE OXIDE THICKNESSES WITHIN THE SAME CHIP	RONSHEIM, PAUL ANDREW

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#### **Inventor Name Search Result**

Your Search was:

Last Name = UTOMO First Name = HENRY

Application#	Patent#	Status	Date Filed	Title	Inventor Name
10710737	Not Issued	71		CHEMICAL TREATMENT TO RETARD DIFFUSION IN A SEMICONDUCTOR OVERLAYER	UTOMO, HENRY K.
10711637	Not Issued	41		STRUCTURE AND METHOD FOR MAKING STRAINED CHANNEL FIELD EFFECT TRANSISTOR USING SACRIFICIAL SPACER	UTOMO, HENRY K.
10905598	Not Issued	30		IN SITU DOPED EMBEDDED SIGE EXTENSION AND SOURCE/DRAIN FOR ENHANCED PFET PERFORMANCE	UTOMO, HENRY K.
10908394	Not Issued	30		EMBEDDED SILICON GERMANIUM USING A DOUBLE BURIED OXIDE SILICON-ON-INSULATOR WAFER	UTOMO, HENRY K.
11163871	Not Issued	20	1	LOW MODULUS SPACERS FOR CHANNEL STRESS ENHANCEMENT	UTOMO, HENRY K.

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